NSN 5961-01-629-0938

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-629-0938 **Inclosure Material:** Plastic **Overall Length:** 30.6 millimeters **Mounting Method:** Press fit **Semiconductor Material:** Gallium arsenide phosphide Voltage Rating In Volts Per Characteristic: 3.0 forward voltage, peak **Current Rating Per Characteristic:** 30.0 milliamperes forward current, repetitive, peak total value **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

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